

# APN-004

## Quantum efficiency of CMOS sensors

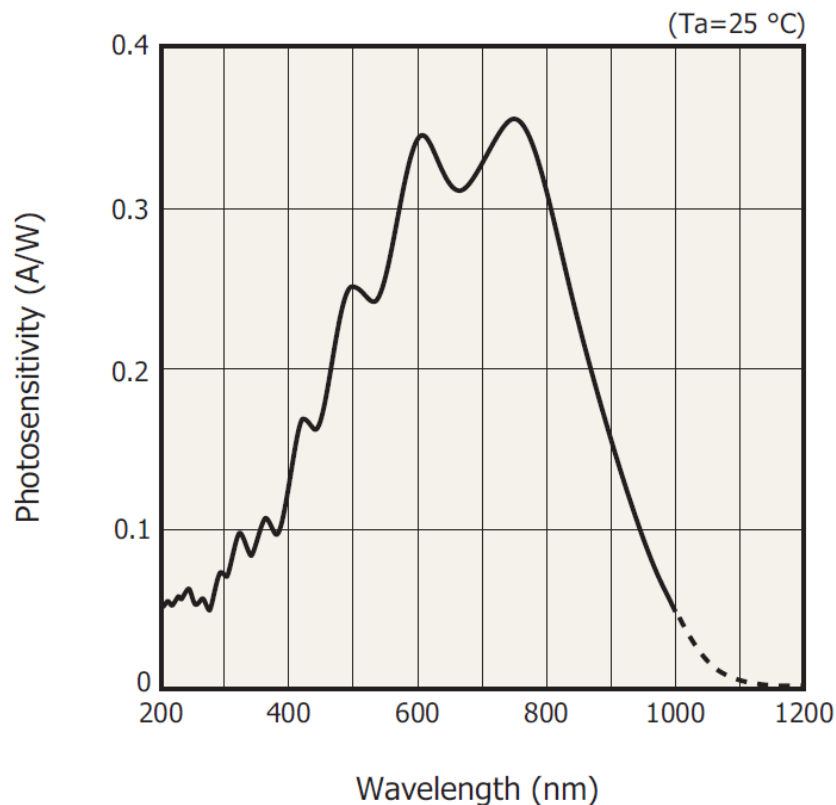


### Overview

Most sensor datasheets don't provide the quantum efficiency (QE) directly. Instead, they provide photosensitivity graphs of A/W versus wavelength. In this article we show how to calculate QE from photosensitivity graphs.

### Photosensitivity graphs

Below is an example of a typical CMOS photosensitivity graph:



The photosensitivity is given in [A/W] and can be converted to QE using the following steps:

1. Extract the image of the graph from the datasheet
2. Digitize the graph using either AI or a graph digitizing tool and generate a CSV file
3. Import the digitized data (CSV of [A/W] versus [nm]) into Excel
4. Postprocess the data and calculate the QE

## Calculate QE from photosensitivity

Photosensitivity consists of:

- Current in [A]: This gives the number of electrons per second
- Light power in [W]: This gives the number of photons per second

### Electrons per second (Fe)

The electron flux,  $F_e$ , can be calculated by dividing the current by the elementary charge  $e^-$ :

$$F_e [e^-/s] = \text{Current [A]} / Q_e = \text{Current [A]} / 1.60217663 \times 10^{-19} [\text{Coulomb}]$$

### Photons per second (Fp)

The photon flux can be calculated by using Planck's law for the energy of a photon:

$$E_p [J] = h.F = h.c / L,$$

where  $h$  is Planck's constant ( $6.62607015 \times 10^{-34} \text{ J.Hz}^{-1}$ ),  $c$  the speed of light ( $299.792458 \times 10^6 \text{ m.s}^{-1}$ ) and  $L$  the wavelength in [m]. The photon flux,  $F_p$ , is the number of photons required to provide 1 W of power:

$$F_p [p/s] = 1 \text{ W} / E_p$$

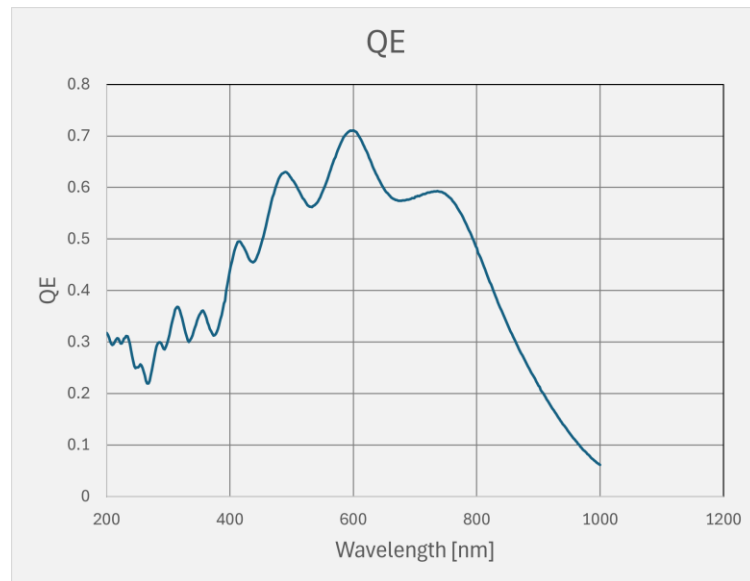
## Quantum efficiency

The QE is given by the number of electrons per photon:

$$QE = F_e / F_p$$

## Results

The above graph was digitized and postprocessed as described. This is the equivalent QE vs. wavelength:



### Observations about CMOS sensors:

- The peak QE is around 70% @ 600 nm
- The QE in the UV range is around 30%
- Above 800 nm the QE drops sharply and is around 10% @ 1000 nm